

LM5164 100-V Input, 1-A synchronous buck DC/DC converter with ultra-low I_Q

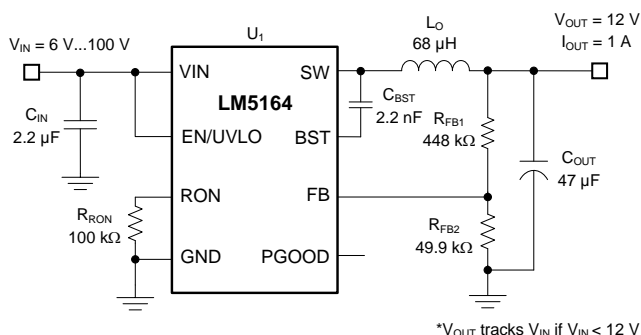
1 Features

- Designed for reliable and rugged applications
 - Wide input voltage range of 6 V to 100 V
 - Junction temperature range: -40°C to $+150^{\circ}\text{C}$
 - Fixed 3-ms internal soft-start timer
 - Peak and valley current-limit protection
 - Input UVLO and thermal shutdown protection
- Suited for scalable Industrial power supplies and battery packs
 - Low minimum on- and off-times of 50 ns
 - Adjustable switching frequency up to 1 MHz
 - Diode emulation for high light-load efficiency
 - 10.5- μA no-load input quiescent current
 - 3- μA shutdown quiescent current
 - Optimized for CISPR 32 EMI standard
- Integration reduces solution size and cost
 - COT mode control architecture
 - Integrated 0.725- Ω NFET buck switch supports wide duty-cycle range
 - Integrated 0.34- Ω NFET synchronous rectifier eliminates external Schottky diode
 - 1.2-V internal voltage reference
 - No loop compensation components
 - Internal VCC bias regulator and boot diode
 - Open-drain power good indicator
 - 8-Pin SOIC package with PowerPAD™
- Create a custom design using [WEBENCH® power designer](#)

2 Applications

- Appliances, power and garden tools
- High-cell-count battery packs (E-Bike, E-Scooter)
- Motor drives, drones, telecom

Typical Application



3 Description

The LM5164 synchronous buck converter is designed to regulate over a wide input voltage range, minimizing the need for external surge suppression components. A minimum controllable on-time of 50 ns facilitates large step-down conversion ratios, enabling the direct step-down from a 48-V nominal input to low-voltage rails for reduced system complexity and solution cost. The LM5164 operates during input voltage dips as low as 6 V, at nearly 100% duty cycle if needed, making it an excellent choice for wide input supply range industrial and high cell count battery pack applications.

With integrated high-side and low-side power MOSFETs, the LM5164 delivers up to 1-A of output current. A constant on-time (COT) control architecture provides nearly constant switching frequency with excellent load and line transient response. Additional features of the LM5164 include ultra-low I_Q and diode emulation mode operation for high light-load efficiency, innovative peak and valley overcurrent protection, integrated VCC bias supply and bootstrap diode, precision enable and input UVLO, and thermal shutdown protection with automatic recovery. An open-drain PGOOD indicator provides sequencing, fault reporting, and output voltage monitoring.

The LM5164 is available in a thermally-enhanced, 8-pin SO PowerPAD™ package. Its 1.27-mm pin pitch provides adequate spacing for high-voltage applications.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|-----------------|-------------------|
| LM5164 | SO PowerPAD (8) | 4.89 mm x 3.90 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Typical Application Efficiency, $V_{OUT} = 12$ V

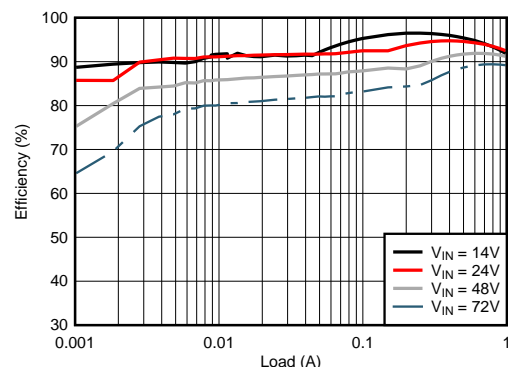


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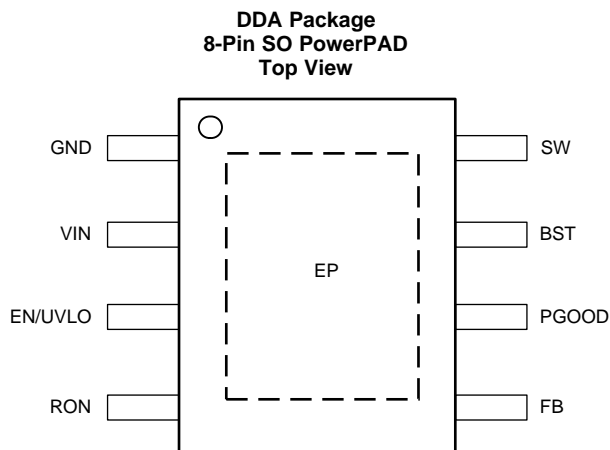
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Original (September 2018) to Revision A | Page |
|--|------|
| • First release of production-data data sheet; add top navigator icon for TI reference design..... | 1 |

5 Pin Configuration and Functions



Pin Functions

| PIN | | I/O ⁽¹⁾ | DESCRIPTION |
|-----|---------|--------------------|--|
| NO. | NAME | | |
| 1 | GND | G | Ground connection for internal circuits. |
| 2 | VIN | P/I | Regulator supply input pin to high-side power MOSFET and internal bias regulator. Connect directly to the input supply of the buck converter with short, low impedance paths. |
| 3 | EN/UVLO | I | Precision enable and undervoltage lockout (UVLO) programming pin. If the EN/UVLO voltage is below 1.1 V, the converter is in the shutdown mode with all functions disabled. If the UVLO voltage is greater than 1.1 V and below 1.5 V, the converter is in standby mode with the internal VCC regulator operational and no switching. If the EN/UVLO voltage is above 1.5 V, the start-up sequence begins. |
| 4 | RON | I | On-time programming pin. A resistor between this pin and GND sets the buck switch on-time. |
| 5 | FB | I | Feedback input of voltage regulation comparator. |
| 6 | PGOOD | O | Power good indicator. This pin is an open-drain output pin. Connect to a source voltage through an external pullup resistor between 10 kΩ to 100 kΩ |
| 7 | BST | P/I | Bootstrap gate-drive supply. Required to connect a high-quality 2.2-nF 50-V X7R ceramic capacitor between BST and SW to bias the internal high-side gate driver. |
| 8 | SW | P | Switching node that is internally connected to the source of the high-side NMOS buck switch and the drain of the low-side NMOS synchronous rectifier. Connect to the switching node of the power inductor. |
| — | EP | — | Exposed pad of the package. No internal electrical connection. Solder the EP to the GND pin and connect to a large copper plane to reduce thermal resistance. |

(1) G = Ground, I = Input, O = Output, P = Power

6 Specifications

6.1 Absolute Maximum Ratings

Over the recommended operating junction temperature range of -40°C to $+150^{\circ}\text{C}$ (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT |
|---------------------------------------|--------------------------------|------|-------|--------------------|
| Input voltage | VIN to GND | −0.3 | 100 | V |
| | EN to GND | −0.3 | 100 | |
| | FB to GND | −0.3 | 5.5 | |
| | RON to GND | −0.3 | 5.5 | |
| Bootstrap capacitor | External BST to SW capacitance | 1.5 | 2.5 | nF |
| Output voltage | BST to GND | −0.3 | 105.5 | V |
| | BST to SW | −0.3 | 5.5 | |
| | SW to GND | −1.5 | 100 | |
| | SW to GND (20-ns transient) | −3 | | |
| | PGOOD to GND | −0.3 | 14 | |
| Operating junction temperature, T_J | | −40 | 150 | $^{\circ}\text{C}$ |
| Storage temperature, T_{stg} | | −65 | 150 | $^{\circ}\text{C}$ |

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| $V_{\text{(ESD)}}$ | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±500 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over the recommended operating junction temperature range of -40°C to $+150^{\circ}\text{C}$ (unless otherwise noted)⁽¹⁾

| | | MIN | NOM | MAX | UNIT |
|----------------------|--------------------------------|-----|-----|-------|------|
| V_{IN} | Input voltage | 6 | | 100 | V |
| V_{SW} | Switch node voltage | | | 100 | V |
| $V_{\text{EN/UVLO}}$ | Enable voltage | | | 100 | V |
| I_{LOAD} | Load current | | 1 | 1.25 | A |
| F_{SW} | Switching frequency | | | 1000 | kHz |
| C_{BST} | External BST to SW capacitance | | 2.2 | | nF |
| t_{ON} | Programmable on-time | 50 | | 10000 | ns |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | LM5164 | UNIT |
|-------------------------------|--|------------|------|
| | | DDA (SOIC) | |
| | | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 41.1 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 37.3 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 30.6 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 6.7 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 24.4 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | 2.4 | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

Typical values correspond to $T_J = 25^\circ\text{C}$. Minimum and maximum limits apply over the full -40°C to 150°C junction temperature range unless otherwise indicated. $V_{IN} = 24\text{ V}$ and $V_{EN/UVLO} = 2\text{ V}$ unless otherwise stated.

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|--|---|-------|-------|-------|---------------|
| SUPPLY CURRENT | | | | | | |
| $I_{Q-SHUTDOWN}$ | VIN shutdown current | $V_{EN} = 0\text{ V}$ | | 3 | 15 | μA |
| $I_{Q-SLEEP1}$ | VIN sleep current | $V_{EN} = 2.5\text{ V}$, $V_{FB} = 1.5\text{ V}$ | | 10.5 | 25 | μA |
| $I_{Q-ACTIVE}$ | VIN active current | $V_{EN} = 2.5\text{ V}$ | | 600 | 880 | μA |
| EN/UVLO | | | | | | |
| $V_{SD-RISING}$ | Shutdown threshold | $V_{EN/UVLO}$ rising | | | 1.1 | V |
| $V_{SD-FALLING}$ | Shutdown threshold | $V_{EN/UVLO}$ falling | 0.45 | | | V |
| $V_{EN-RISING}$ | Enable threshold | $V_{EN/UVLO}$ rising | 1.45 | 1.5 | 1.55 | V |
| $V_{EN-FALLING}$ | Enable threshold | $V_{EN/UVLO}$ falling | 1.35 | 1.4 | 1.44 | V |
| FEEDBACK | | | | | | |
| V_{REF} | FB regulation voltage | V_{FB} falling | 1.181 | 1.2 | 1.218 | V |
| TIMING | | | | | | |
| t_{ON1} | On-time1 | $V_{VIN} = 6\text{ V}$, $R_{RON} = 75\text{ k}\Omega$ | | 5000 | | ns |
| t_{ON2} | On-time2 | $V_{VIN} = 6\text{ V}$, $R_{RON} = 25\text{ k}\Omega$ | | 650 | | ns |
| t_{ON3} | On-time3 | $V_{VIN} = 12\text{ V}$, $R_{RON} = 75\text{ k}\Omega$ | | 2550 | | ns |
| t_{ON4} | On-time4 | $V_{VIN} = 12\text{ V}$, $R_{RON} = 25\text{ k}\Omega$ | | 830 | | ns |
| PGOOD | | | | | | |
| V_{PG-UTH} | FB upper threshold for PGOOD high to low | V_{FB} rising | 1.105 | 1.14 | 1.175 | V |
| V_{PG-LTH} | FB lower threshold for PGOOD high to low | V_{FB} falling | 1.055 | 1.08 | 1.1 | V |
| V_{PG-HYS} | PGOOD upper and lower threshold hysteresis | V_{FB} falling | | 60 | | mV |
| R_{PG} | PGOOD pulldown resistance | $V_{FB} = 1\text{ V}$ | | 30 | | Ω |
| BOOTSTRAP | | | | | | |
| V_{BST-UV} | Gate drive UVLO | V_{BST} rising | | 2.7 | 3.4 | V |
| POWER SWITCHES | | | | | | |
| $R_{DS(on)-HS}$ | High-side MOSFET $R_{DS(on)}$ | $I_{SW} = -100\text{ mA}$ | | 0.725 | | Ω |
| $R_{DS(on)-LS}$ | Low-side MOSFET $R_{DS(on)}$ | $I_{SW} = 100\text{ mA}$ | | 0.34 | | Ω |

Electrical Characteristics (continued)

Typical values correspond to $T_J = 25^{\circ}\text{C}$. Minimum and maximum limits apply over the full -40°C to 150°C junction temperature range unless otherwise indicated. $V_{IN} = 24\text{ V}$ and $V_{ENVLO} = 2\text{ V}$ unless otherwise stated.

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|--|-----------------------|------|-----|------|------|
| SOFT START | | | | | | |
| t _{SS} | Internal soft-start time | | 1.75 | 3 | 4.75 | ms |
| CURRENT LIMIT | | | | | | |
| I _{PEAK1} | Peak current limit threshold (HS) | | 1.25 | 1.5 | 1.75 | A |
| I _{PEAK2} | Peak current limit threshold (LS) | | 1.25 | 1.5 | 1.75 | A |
| I _{DELTA-ILIM} | Min of (I _{PEAK1} or I _{PEAK2}) minus I _{VALLEY} | | 200 | 300 | | mA |
| I _{VALLEY} | Valley current limit threshold | | 0.95 | 1.2 | 1.4 | A |
| THERMAL SHUTDOWN | | | | | | |
| T _{SD} | Thermal shutdown threshold | T _J rising | 175 | | | °C |
| T _{SD-HYS} | Thermal shutdown hysteresis | | 10 | | | °C |

6.6 Typical Characteristics

At $T_A = 25^\circ\text{C}$, $V_{OUT} = 12\text{ V}$, $L_O = 68\text{ }\mu\text{H}$, $R_{RON} = 105\text{ k}\Omega$, unless otherwise specified. .

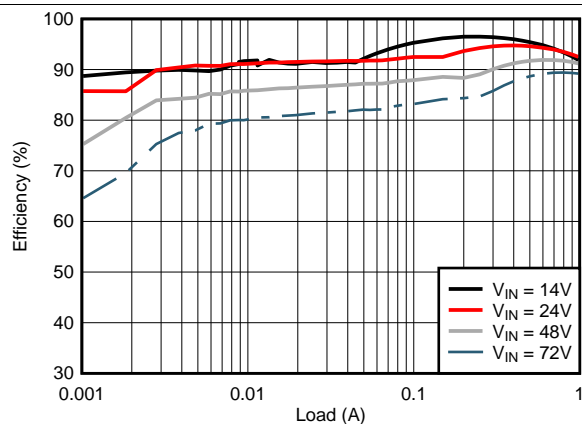


Figure 1. Conversion Efficiency (Log Scale)

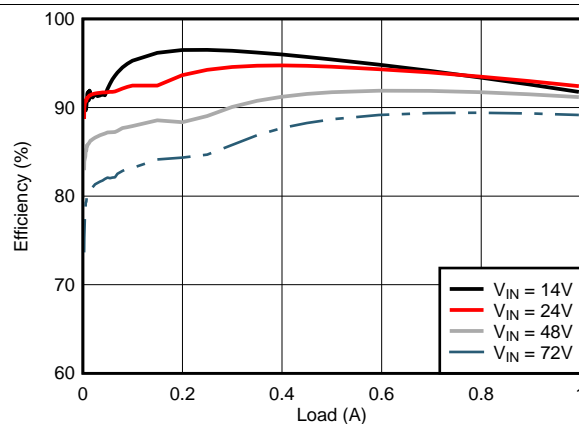


Figure 2. Conversion Efficiency (Linear Scale)

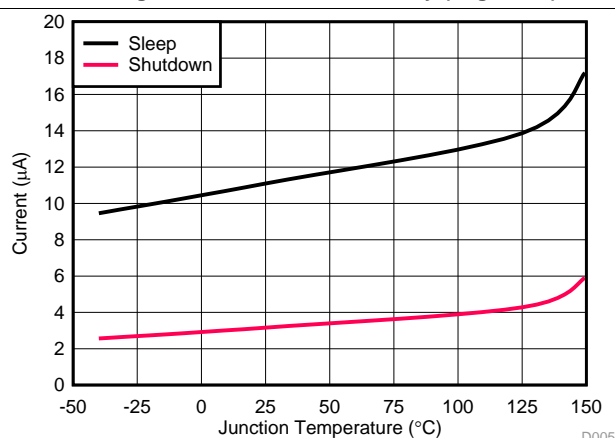


Figure 3. V_{IN} Shutdown and Sleep Supply Current vs Temperature

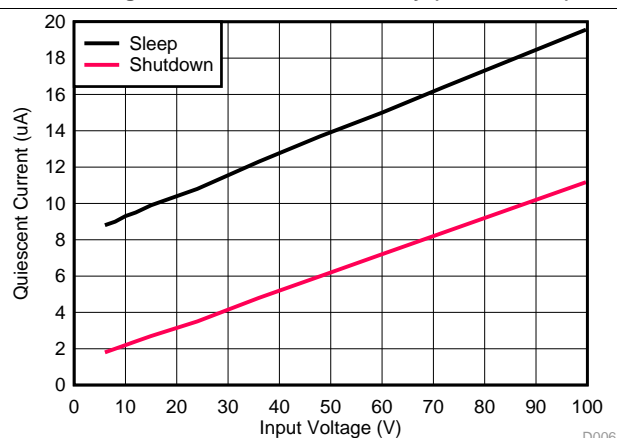


Figure 4. V_{IN} Shutdown and Sleep Supply Current vs Input Voltage

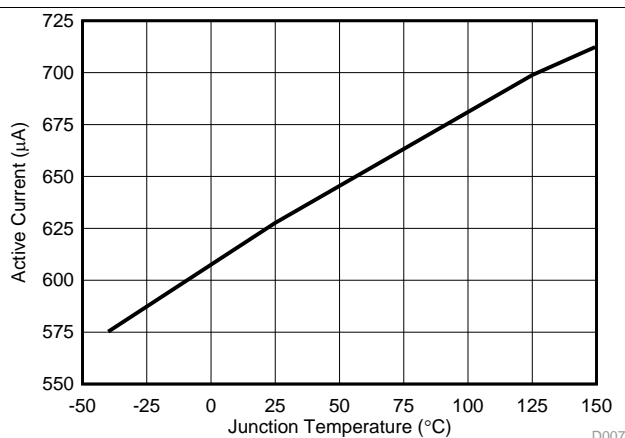


Figure 5. V_{IN} Active Current vs Temperature

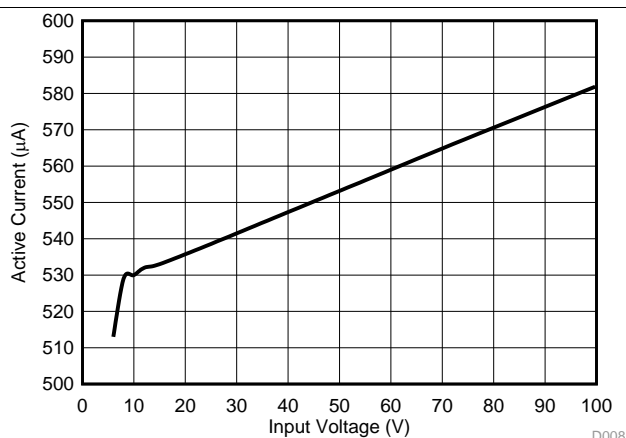


Figure 6. V_{IN} Active Current vs Input Voltage

Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{OUT} = 12\text{ V}$, $L_O = 68\text{ }\mu\text{H}$, $R_{RON} = 105\text{ k}\Omega$, unless otherwise specified. .

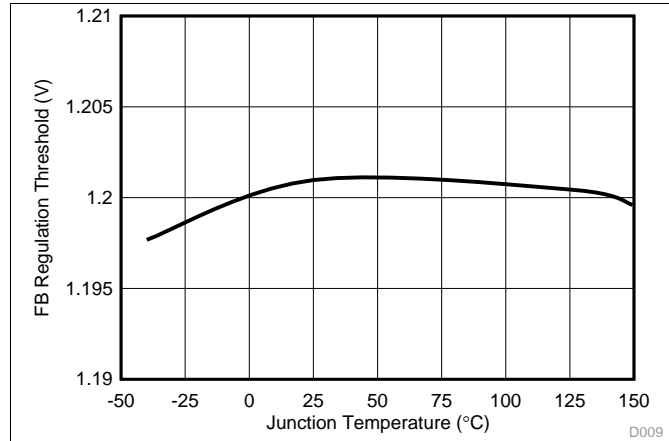


Figure 7. Feedback Comparator Threshold vs Temperature

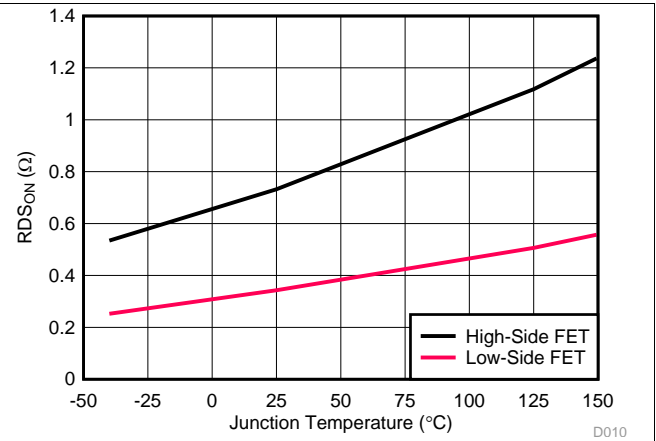


Figure 8. MOSFETs On-State Resistance vs Temperature

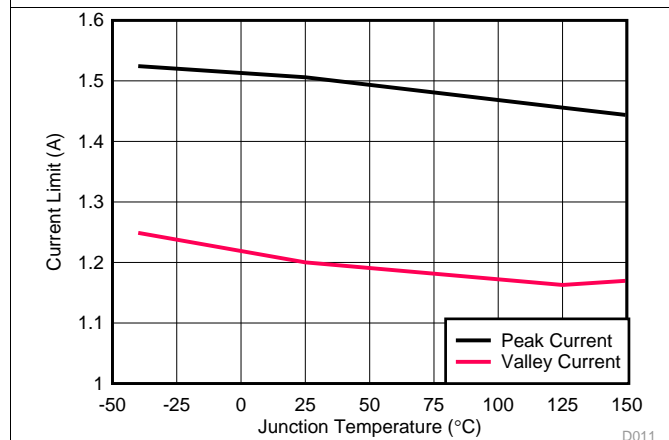


Figure 9. Peak and Valley Current Limit vs Temperature

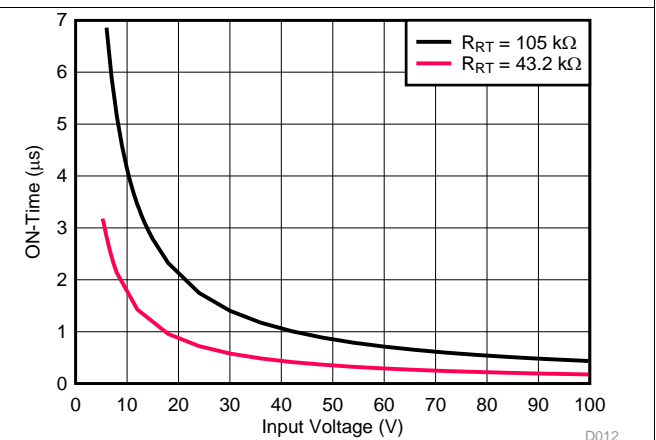


Figure 10. COT On-Time vs V_{IN}

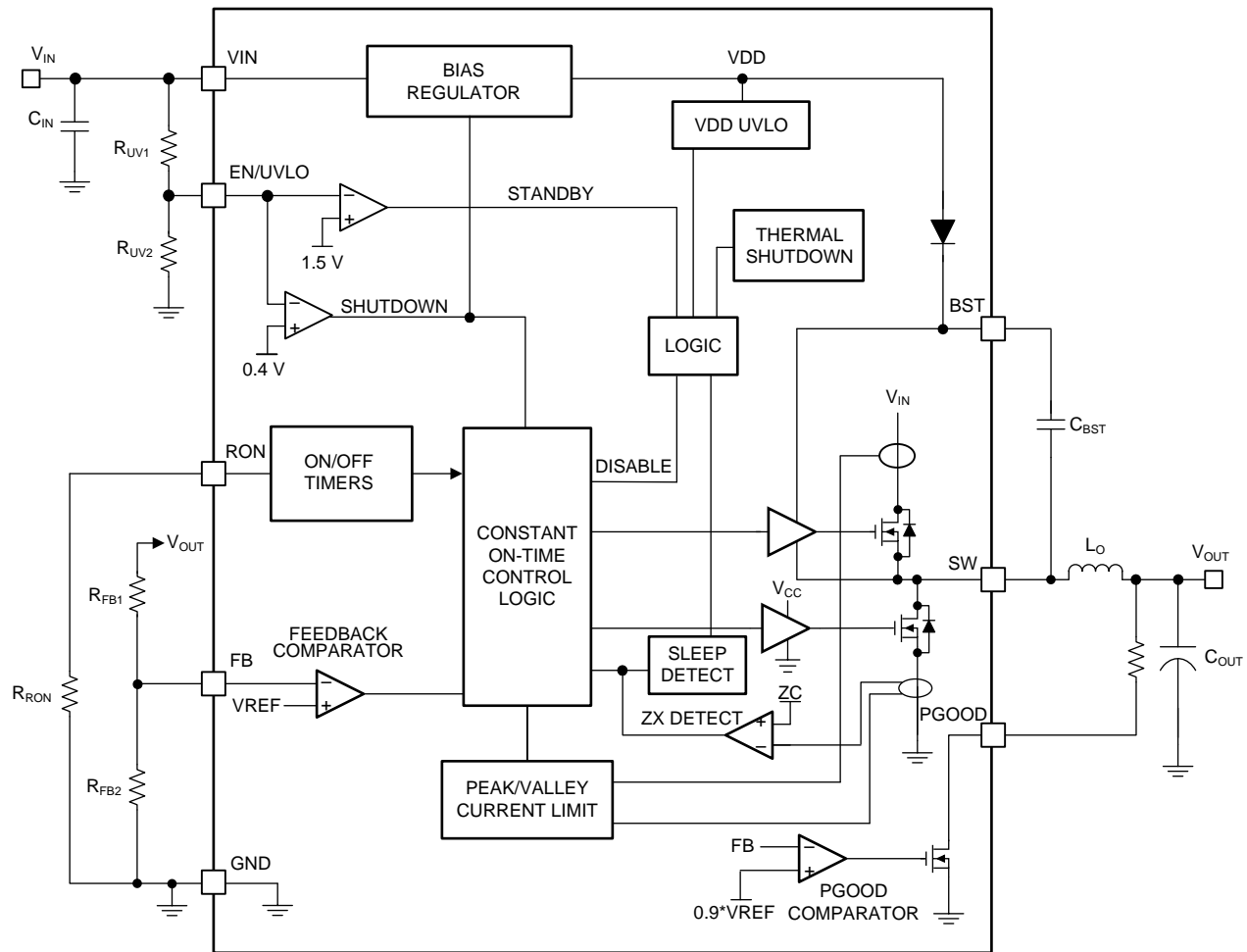
7 Detailed Description

7.1 Overview

The LM5164 is an easy-to-use, ultra-low I_Q constant on-time (COT) synchronous step-down buck regulator. With integrated high-side and low-side power MOSFETs, the LM5164 is a low-cost, highly efficient buck converter that operates from a wide input voltage of 6 V to 100 V, delivering up to 1-A DC load current. The LM5164 is available in the 8-pin SO PowerPAD package. This constant on-time (COT) converter is ideal for low-noise, high-current, and fast load transient requirements, operating with a predictive on-time switching pulse. Over the input voltage range, input voltage feedforward is employed to achieve a quasi-fixed switching frequency. A controllable on-time as low as 50 ns permits high step-down ratios and a minimum forced off-time of 50 ns provides extremely high duty cycles allowing V_{IN} to drop close to V_{OUT} before frequency foldback occurs. At light loads the device transitions into an ultra-low I_Q mode to maintain high efficiency and prevent draining battery cells connected to the input when the system is in standby. The LM5164 implements a smart peak and valley current limit detection circuit to ensure robust protection during output short circuit conditions. Control loop compensation is not required for this regulator, reducing design time and external component count.

The LM5164 incorporates additional features for comprehensive system requirements, including an open-drain Power Good circuit for power-rail sequencing and fault reporting, internally-fixed soft start, monotonic start-up into prebiased loads, precision enable for programmable line undervoltage lockout (UVLO), smart cycle-by-cycle current limit for optimal inductor sizing, and thermal shutdown with automatic recovery. These features enable a flexible and easy-to-use platform for a wide range of applications. The LM5164 supports a wide range of end-equipment systems requiring a regulated output from a high input supply where the transient voltage deviates from its DC level. Examples of such end equipment systems are 48-V automotive systems, high cell-count battery-pack systems, 24-V industrial systems, and 48-V telecom and PoE voltage ranges. The pin arrangement is designed for a simple layout requiring only a few external components.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Control Architecture

The LM5164 step-down switching converter employs a constant on time (COT) control scheme. The COT control scheme sets a fixed on-time t_{ON} of the high-side FET using a timing resistor (R_{ON}). The t_{ON} is adjusted as V_{IN} changes and is inversely proportion to input voltage to maintain a fixed frequency when in continuous conduction mode (CCM). After expiration of t_{ON} , the high side FET remains off until the feedback pin is equal or below the reference voltage of 1.2 V. In order to maintain stability, the feedback comparator requires a minimal ripple voltage that is in phase with the inductor current during the off-time. Furthermore, this change in feedback voltage during the off-time must be large enough to dominate any noise present at the feedback node. The minimum recommended ripple voltage is 20 mV. Refer to [Table 1](#) for different types of ripple injection schemes that ensure stability over the full input voltage range.

During a rapid start-up or a positive load step, the regulator operates with minimum off-times until regulation is achieved. This feature enables extremely fast load transient response with minimum output voltage undershoot. When regulating the output in steady-state operation, the off-time automatically adjusts itself to produce the SW-pin duty cycle required for output voltage regulation to maintain a fixed switching frequency. In CCM the operating frequency F_{SW} is programmed by the R_{ON} resistor and can be calculated using [Equation 1](#).

$$F_{SW} \text{ (kHz)} = \frac{V_{OUT} \text{ (V)} \cdot 2500}{R_{ON} \text{ (k}\Omega\text{)}} \quad (1)$$

Feature Description (continued)

Table 1. Ripple Generation Methods

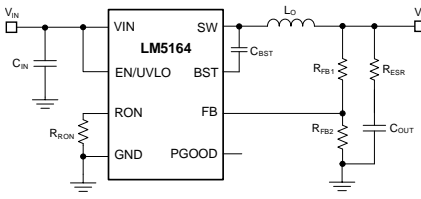
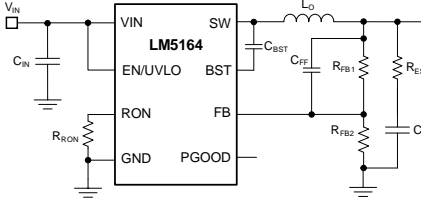
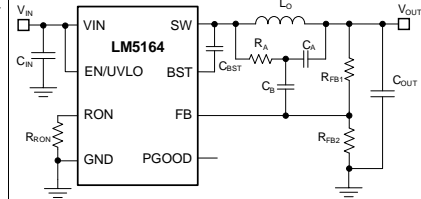
| TYPE 1 | TYPE 2 | TYPE 3 |
|---|---|--|
| Lowest Cost | Reduced Ripple | Minimum Ripple |
|  |  |  |
| $R_{ESR} \geq \frac{20\text{mV} \cdot V_{OUT}}{V_{FB1} \cdot \Delta I_{L(nom)}}$ $R_{ESR} \geq \frac{V_{OUT}}{2 \cdot V_{IN} \cdot F_{SW} \cdot C_{OUT}}$ | $R_{ESR} \geq \frac{20\text{mV}}{\Delta I_{L(nom)}}$ $R_{ESR} \geq \frac{V_{OUT}}{2 \cdot V_{IN} \cdot F_{SW} \cdot C_{OUT}}$ $C_{FF} \geq \frac{1}{2\pi \cdot F_{SW} \cdot (R_{FB1} \parallel R_{FB2})}$ | $C_A \geq \frac{10}{F_{SW} \cdot (R_{FB1} \parallel R_{FB2})}$ $R_A C_A \leq \frac{(V_{IN(nom)} - V_{OUT}) \cdot t_{ON} (@V_{IN(nom)})}{20\text{mV}}$ $C_B \geq \frac{t_{TR-settling}}{3 \cdot R_{FB1}}$ |

Table 1 presents 3 different methods for generating appropriate voltage ripple at the feedback node. Type-1 ripple generation method uses a single resistor, R_{ESR} in series with the output capacitor. The generated voltage ripple has two components, capacitive ripple caused by the inductor ripple current charging and discharging the output capacitor and resistive ripple caused by the inductor ripple current flowing into the output capacitor and through series resistance R_{ESR} . The capacitive ripple component is out of phase with the inductor current and does not decrease monotonically during the off-time. The resistive ripple component is in phase with the inductor current and decreases monotonically during the off-time. The resistive ripple must exceed the capacitive ripple at V_{OUT} for stable operation. If this condition is not satisfied, unstable switching behavior is observed in COT converters, with multiple on-time bursts in close succession followed by a long off time. Equation 2 and Equation 3 define the value of the series resistance R_{ESR} to ensure sufficient in-phase ripple at the feedback node.

Type-2 ripple generation uses a C_{FF} capacitor in addition to the series resistor. As the output voltage ripple is directly AC-coupled by C_{FF} to the feedback node, the R_{ESR} and ultimately the output voltage ripple are reduced by a factor of V_{OUT} / V_{FB1} .

Type-3 ripple generation uses an RC network consisting of R_A and C_A , and the switch node voltage to generate a triangular ramp that is in-phase with the inductor current. This triangular wave is the AC-coupled into the feedback node with capacitor C_B . Because this circuit does not use output voltage ripple, it is suited for applications where low output voltage ripple is critical. TI application note [AN-1481 Controlling Output ripple and achieving ESR independence in constant on-time \(COT\) regulator designs](#) provides additional details on this topic.

Diode emulation mode (DEM) prevents negative inductor current, and pulse skipping maintains highest efficiency at light load currents by decreasing the effective switching frequency. DEM operation occurs when the synchronous power MOSFET switches off as inductor valley current reaches zero. Here, the load current is less than half of the peak-to-peak inductor current ripple in CCM. Turning off the low-side MOSFET at zero current reduces switching loss, and preventing negative current conduction reduces conduction loss. Power conversion efficiency is thus higher in a DEM converter than an equivalent forced-PWM CCM converter. With DEM operation, the duration that both power MOSFETs remain off progressively increases as load current decreases. When this idle duration exceeds 15 μs , the converter transitions into an ultra-low I_Q mode, consuming only 10- μA quiescent current from the input.

Feature Description (continued)

7.3.2 Internal VCC Regulator and Bootstrap Capacitor

The LM5164 contains an internal linear regulator that is powered from VIN with a nominal output of 5 V, eliminating the need for an external capacitor to stabilize the linear regulator. The internal VCC regulator supplies current to internal circuit blocks including the synchronous FET driver and logic circuits. The input pin (VIN) can be connected directly to line voltages up to 100 V. As the power MOSFET has a low total gate charge, use a low bootstrap capacitor value to reduce the stress on the internal regulator. It is required to select a high-quality 2.2-nF 50-V X7R ceramic bootstrap capacitor as specified in the [Absolute Maximum Ratings](#). Selecting a higher value capacitance stresses the internal VCC regulator and damages the device. A lower capacitance than required may not be sufficient to drive the internal gate of the power MOSFET. An internal diode connects from the linear regulator to the BST pin to replenish the charge in the high-side gate drive bootstrap capacitor when the SW voltage is low.

7.3.3 Regulation Comparator

The feedback voltage at FB is compared to an internal 1.2-V reference. The LM5164 voltage regulation loop regulates the output voltage by maintaining the FB voltage equal to the internal reference voltage, VREF. A resistor divider programs the ratio from output voltage VOUT to FB. For a target VOUT setpoint, calculate RFB2 based on the selected RFB1 using [Equation 10](#).

$$R_{FB2} = \frac{1.2V}{V_{OUT} - 1.2V} \cdot R_{FB1} \quad (10)$$

TI recommends selecting RFB1 in the range of 100 kΩ to 1 MΩ for most applications. A larger RFB1 consumes less DC current, which is mandatory if light-load efficiency is critical. RFB1 larger than 1 MΩ is not recommended as the feedback path becomes more susceptible to noise. It is important to route the feedback trace away from the noisy area of the PCB and keep the feedback resistors close to the FB pin.

7.3.4 Internal Soft Start

The LM5164 employs an internal soft-start control ramp that allows the output voltage to gradually reach a steady-state operating point, thereby reducing start-up stresses and current surges. The soft-start feature produces a controlled, monotonic output voltage start-up. The soft-start time is internally set to 3 ms.

7.3.5 ON-Time Generator

The on-time of the LM5164 high-side FET is determined by the RRON resistor and is inversely proportional to the input voltage, VIN. The inverse relationship with VIN results in a nearly constant frequency as VIN is varied. Calculate the on-time using [Equation 11](#).

$$t_{ON}(\mu s) = \frac{R_{RON}(k\Omega)}{V_{IN}(V) \cdot 2.5} \quad (11)$$

Determine the RRON resistor using [Equation 12](#) to set a specific switching frequency in CCM.

$$R_{RON}(k\Omega) = \frac{V_{OUT}(V) \cdot 2500}{F_{SW}(kHz)} \quad (12)$$

Select RRON for a minimum on-time (at maximum VIN) greater than 50 ns for proper operation. In addition to this minimum on-time, the maximum frequency for this device is limited to 1 MHz.

7.3.6 Current Limit

The LM5164 manages overcurrent conditions with cycle-by-cycle current limiting of the peak inductor current. The current sensed in the high-side MOSFET is compared every switching cycle to the current limit threshold (1.5 A). To protect the converter from potential current runaway conditions, the LM5164 includes a fold-back valley current limit feature, set at 1.2 A, that is enabled if a peak current limit is detected. As shown in [Figure 11](#), if the peak current in the high-side MOSFET exceeds 1.5 A (typical), the present cycle is immediately terminated

Feature Description (continued)

regardless of the programmed on-time (t_{ON}), the high-side MOSFET is turned off and the fold-back valley current limit is activated. The low-side MOSFET remains on until the inductor current drops below this fold-back valley current limit, after which the next on-pulse is initiated. This method folds back the switching frequency to prevent overheating and limits the average output current to less than 1.5 A to ensure proper short-circuit and heavy-load protection of the LM5164.

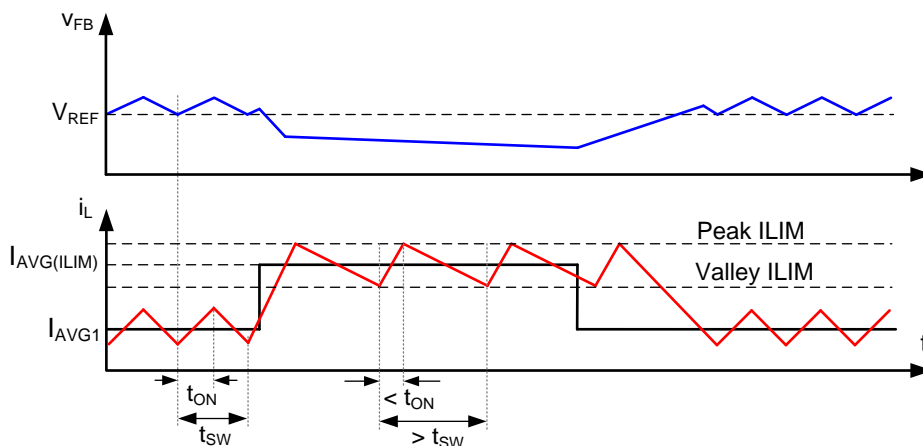


Figure 11. Current Limit Timing Diagram

Current is sensed after a leading-edge blanking time following the high-side MOSFET turnon transition. The propagation delay of the current limit comparator is 100 ns. During high step-down conditions when the on-time is less than 100 ns, a back-up peak current limit comparator in the low-side FET also set at 1.5 A will enable the fold-back valley current limit set at 1.2 A. This innovative current limit scheme enables ultra-low duty-cycle operation permitting large step down voltage conversions while ensuring robust protection of the converter.

7.3.7 N-Channel Buck Switch and Driver

The LM5164 integrates an N-channel buck switch and associated floating high-side gate driver. The gate-driver circuit works in conjunction with an external bootstrap capacitor and an internal high-voltage bootstrap diode. A high-quality 2.2-nF, 50-V X7R ceramic capacitor connected between the BST and SW pins provides the voltage to the high-side driver during the buck switch on-time. See [Internal VCC Regulator and Bootstrap Capacitor](#) for limitations. During the off-time, the SW pin is pulled down to approximately 0 V, and the bootstrap capacitor charges from the internal VCC through the internal bootstrap diode. The minimum off-timer, set to 50 ns (typical), ensures a minimum time each cycle to recharge the bootstrap capacitor. When the on-time is less than 300ns, the minimum off-timer is forced to 250 ns to ensure that the BST capacitor is charged in a single cycle. This is vital during wake up from sleep mode when the BST capacitor is most likely discharged.

7.3.8 Synchronous Rectifier

The LM5164 provides an internal low-side synchronous rectifier N-channel MOSFET. This MOSFET provides a low-resistance path for the inductor current to flow when the high-side MOSFET is turned off.

The synchronous rectifier operates in a diode emulation mode. Diode emulation enables the regulator to operate in a pulse-skipping mode during light load conditions. This mode leads to a reduction in the average switching frequency at light loads. Switching losses and FET gate driver losses, both of which are proportional to switching frequency, are significantly reduced at very light loads and efficiency is improved. This pulse-skipping mode also reduces the circulating inductor current and losses associated with conventional CCM at light loads.

Feature Description (continued)

7.3.9 Enable/Undervoltage Lockout (EN/UVLO)

The LM5164 contains a dual-level EN/UVLO circuit. When the EN/UVLO voltage is below 1.1 V (typical), the converter is in a low-current shutdown mode and the input quiescent current (I_Q) is dropped down to 3 μ A. When the voltage is greater than 1.1 V but less than 1.5 V (typical), the converter is in standby mode. In standby mode the internal bias regulator is active while the control circuit is disabled. When the voltage exceeds the rising threshold of 1.5 V (typical), normal operation begins. Install a resistor divider from VIN to GND to set the minimum operating voltage of the regulator. Use [Equation 13](#) and [Equation 14](#) to calculate the input UVLO turnon and turnoff voltages, respectively.

$$V_{IN(on)} = 1.5 \text{ V} \cdot \left(1 + \frac{R_{UV1}}{R_{UV2}} \right) \quad (13)$$

$$V_{IN(off)} = 1.4 \text{ V} \cdot \left(1 + \frac{R_{UV1}}{R_{UV2}} \right) \quad (14)$$

TI recommends selecting R_{UV1} in the range of 1 M Ω for most applications. A larger R_{UV1} consumes less DC current, which is mandatory if light-load efficiency is critical. If input UVLO is not required, the power-supply designer can either drive EN/UVLO as an enable input driven by a logic signal or connect it directly to VIN. If EN/UVLO is directly connected to VIN, the regulator begins switching as soon as the internal bias rails are active.

7.3.10 Power Good (PGOOD)

The LM5164 provides a PGOOD flag pin to indicate when the output voltage is within the regulation level. Use the PGOOD signal for start-up sequencing of downstream converters or for fault protection and output monitoring. PGOOD is an open-drain output that requires a pullup resistor to a DC supply not greater than 14 V. The typical range of pullup resistance is 10 k Ω to 100 k Ω . If necessary, use a resistor divider to decrease the voltage from a higher voltage pullup rail. When the FB voltage exceeds 95% of the internal reference V_{REF} , the internal PGOOD switch turns off and PGOOD can be pulled high by the external pullup. If the FB voltage falls below 90% of V_{REF} , an internal 25- Ω PGOOD switch turns on and PGOOD is pulled low to indicate that the output voltage is out of regulation. The rising edge of PGOOD has a built-in deglitch delay of 5 μ s.

7.3.11 Thermal Protection

The LM5164 includes an internal junction temperature monitor to protect the device in the event of a higher than normal junction temperature. If the junction temperature exceeds 175°C (typical), thermal shutdown occurs to prevent further power dissipation and temperature rise. The LM5164 initiates a restart sequence when the junction temperature falls to 165°C, based on a typical thermal shutdown hysteresis of 10°C. This is a non-latching protection, and, as such, the device cycles into and out of thermal shutdown if the fault persists.

7.4 Device Functional Modes

7.4.1 Shutdown Mode

EN/UVLO provides ON and OFF control for the LM5164. When $V_{EN/UVLO}$ is below approximately 1.1 V, the device is in shutdown mode. Both the internal linear regulator and the switching regulator are off. The quiescent current in shutdown mode drops to 3 μA at $V_{IN} = 24\text{ V}$. The LM5164 also employs internal bias rail undervoltage protection. If the internal bias supply voltage is below its UV threshold, the regulator remains off.

7.4.2 Active Mode

The LM5164 is in active mode when $V_{EN/UVLO}$ is above the precision enable threshold and the internal bias rail is above its UV threshold. In COT active mode, the LM5164 is in one of three modes depending on the load current:

1. CCM with fixed switching frequency when load current is above half of the peak-to-peak inductor current ripple
2. Pulse skipping and diode emulation mode (DEM) when the load current is less than half of the peak-to-peak inductor current ripple in CCM operation
3. Current limit CCM with peak and valley current limit protection when an overcurrent condition is applied at the output.

7.4.3 Sleep Mode

[Control Architecture](#) gives a brief introduction to the LM5164 diode emulation (DEM) feature. The converter enters DEM during light-load conditions when the inductor current decays to zero and the synchronous MOSFET is turned off to prevent negative current in the system. In the DEM state, the load current is lower than half the peak-to-peak inductor current ripple and the switching frequency decreases when the load is further decreased as the device operates in a pulse skipping mode. A switching pulse is set when V_{FB} drops below 1.2 V.

As the frequency of operation decreases and V_{FB} remains above 1.2 V (V_{REF}) with the output capacitor sourcing the load current for greater than 15 μs , the converter enters an ultra-low I_Q sleep mode to prevent draining the input power supply. The input quiescent current (I_Q) required by the LM5164 decreases to 10 μA in sleep mode, improving the light-load efficiency of the regulator. In this mode all internal controller circuits are turned off to ensure very low current consumption by the device. Such low I_Q renders the LM5164 as the best option to extend operating lifetime for off-battery applications. The FB comparator and internal bias rail are active to detect when the FB voltage drops below the internal reference V_{REF} and the converter transitions out of sleep mode into active mode. There is a 9 μs wake-up delay from sleep to active states.

8 Application and Implementation

NOTE


Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM5164 requires only a few external components to step down from a wide range of supply voltages to a fixed output voltage. Several features are integrated to meet system design requirements, including precision enable, input voltage UVLO, internal soft start, programmable switching frequency, and a PGOOD indicator.

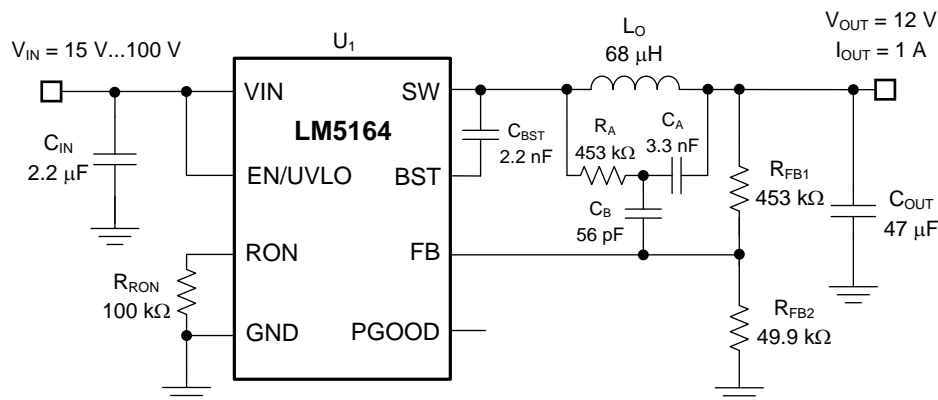
To expedite and streamline the process of designing of a LM5164-based converter, a comprehensive LM5164 [Quickstart calculator](#) is available for download to assist the designer with component selection for a given application. This tool is complemented by the availability of an [evaluation module \(EVM\)](#), numerous PSPICE models, as well as TI's [WEBENCH® Power Designer](#).

8.2 Typical Application



For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation and test results of an LM5164-powered implementation, see [TI Designs](#) reference design library.

The schematic of a 12-V, 1-A COT converter is shown in [Figure 12](#).



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Figure 12. Typical Application $V_{IN(nom)} = 48\text{ V}$, $V_{OUT} = 12\text{ V}$, $I_{OUT(max)} = 1\text{ A}$, $F_{SW(nom)} = 300\text{ kHz}$

NOTE

This and subsequent design examples are provided herein to showcase the LM5164 converter in several different applications. Depending on the source impedance of the input supply bus, an electrolytic capacitor may be required at the input to ensure stability, particularly at low input voltage and high output current operating conditions. See [Power Supply Recommendations](#) for more detail.

8.2.1 Design Requirements

The target full-load efficiency is 92% based on a nominal input voltage of 48 V and an output voltage of 12 V. The required input voltage range is 15 V to 100 V. The LM5164 delivers a fixed 12-V output voltage. The switching frequency is set by resistor R_{RON} at 300 kHz. The output voltage soft-start time is 3 ms. The required components are listed in Table 2. Refer to the [LM5164-Q1EVM-041](#) EVM user's guide for more detail.

Table 2. List of Components

| COUNT | REF DES | VALUE | DESCRIPTION | PART NUMBER | MANUFACTURER |
|-------|------------------|-----------------|---|----------------------|---------------|
| 2 | C _{IN} | 2.2 μ F | Capacitor, Ceramic, 2.2 μ F, 100V, X7R, 10% | CGA6N3X7R2A225K230AB | TDK |
| 1 | C _{OUT} | 22 μ F | Capacitor, Ceramic, 22 μ F, 25V, X7R, 10% | TMK325B7226KMHT | Taiyo Yuden |
| 1 | C _A | 3300 pF | Capacitor, Ceramic, 3300pF, 16V, X7R, 10% | CGA3E2X7R2A332K080AA | TDK |
| 1 | C _B | 56 pF | Capacitor, Ceramic, 56pF, 50V, X7R, 10% | C0603C560J5GACTU | Kemet |
| 1 | C _{BST} | 2.2 nF | Capacitor, Ceramic, 2200pF, 50V, X7R, 10% | GCM155R71H222KA37D | MuRata |
| 1 | L _F | 68 μ H | Inductor, 68 μ H, 170 m Ω , >1.8A | MSS1246T-683MLB | Coilcraft |
| 1 | R _{RON} | 100 k Ω | Resistor, Chip, 100 k, 1%, 0.1 W, 0603 | RG1608P-1053-B-T5 | Susumu Co Ltd |
| 1 | R _{FB1} | 453 k Ω | Resistor, Chip, 453 k, 1%, 0.1 W, 0603 | RT0603BRD07448KL | Yageo |
| 1 | R _{FB2} | 49.9 k Ω | Resistor, Chip, 49.9 k, 1%, 0.1 W, 0603 | RG1608P-4992-B-T5 | Susumu Co Ltd |
| 1 | R _A | 453 k Ω | Resistor, Chip, 453 k, 1%, 0.1W, 0603 | RT0603BRD07453KL | Yageo |
| 1 | U ₁ | | Wide V _{IN} synchronous buck converter | LM5164DDAR | TI |

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the LM5164 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 Switching Frequency (R_{RON})

The switching frequency of LM5164 is set by the on-time programming resistor placed at R_{ON}. As shown by Equation 15, a standard 100 k Ω , 1% resistor sets the switching frequency at 300 kHz.

$$R_{RON}(k\Omega) = \frac{V_{OUT}(V) \cdot 2500}{F_{SW}(kHz)} \quad (15)$$

Note that at very low duty cycles, the 50 ns minimum controllable on-time of the high-side MOSFET, $t_{ON(min)}$, limits the maximum switching frequency. In CCM, $t_{ON(min)}$ limits the voltage conversion step-down ratio for a given switching frequency. Calculate the minimum controllable duty cycle using Equation 16.

$$D_{MIN} = t_{ON(min)} \cdot F_{SW} \quad (16)$$

Ultimately, the choice of switching frequency for a given output voltage affects the available input voltage range, solution size and efficiency. The maximum supply voltage for a given $t_{ON(min)}$ before switching frequency reduction occurs is given by Equation 17.

$$V_{IN(max)} = \frac{V_{OUT}}{t_{ON(min)} \cdot F_{SW}} \quad (17)$$

8.2.2.3 Buck Inductor (L_O)

The inductor ripple current (assuming CCM operation) and peak inductor current are given respectively by [Equation 18](#) and [Equation 19](#).

$$\Delta I_L = \frac{V_{OUT}}{F_{SW} \cdot L_O} \cdot \left(1 - \frac{V_{OUT}}{V_{IN}} \right) \quad (18)$$

$$I_{L(peak)} = I_{OUT(max)} + \frac{\Delta I_L}{2} \quad (19)$$

For most applications, choose an inductance such that the inductor ripple current, ΔI_L , is between 30% and 50% of the rated load current at nominal input voltage. Calculate the inductance using [Equation 20](#).

$$L_O = \frac{V_{OUT}}{F_{SW} \cdot \Delta I_L} \cdot \left(1 - \frac{V_{OUT}}{V_{IN(nom)}} \right) \quad (20)$$

Choosing a 68- μ H inductor in this design results in 447-mA peak-to-peak ripple current at a nominal input voltage of 48 V, equivalent to 45% of the 1-A rated load current.

Check the inductor data sheet to make sure the saturation current of the inductor is well above the current limit setting of the LM5164. Ferrite-core inductors have relatively lower core losses and are preferred at high switching frequencies, but exhibit a hard saturation characteristic – the inductance collapses abruptly when the saturation current is exceeded. This results in an abrupt increase in inductor ripple current, higher output voltage ripple, and reduced efficiency in turn compromising reliability. Note that inductor saturation current levels generally decrease as the core temperature increases.

8.2.2.4 Output Capacitor (C_{OUT})

Select a ceramic output capacitor to limit the capacitive voltage ripple at the converter output. This is the sinusoidal ripple voltage that is generated from the triangular inductor current ripple flowing into and out of the capacitor. Select an output capacitance using [Equation 21](#) to limit the voltage ripple component to 0.5% of the output voltage.

$$C_{OUT} \geq \frac{\Delta I_L}{8 \cdot F_{SW} \cdot V_{OUT(ripple)}} \quad (21)$$

Substituting $\Delta I_{L(nom)}$ of 447 mA gives C_{OUT} greater than 3.1 μ F. With voltage coefficients of ceramic capacitors taken in consideration, a 22- μ F, 25-V rated capacitor with X7R dielectric is selected.

8.2.2.5 Input Capacitor (C_{IN})

An input capacitor is necessary to limit the input ripple voltage while providing AC current to the buck power stage at every switching cycle. To minimize the parasitic inductance in the switching loop, position the input capacitors as close as possible to the VIN and GND pins of the LM5164. The input capacitors conduct a square-wave current of peak-to-peak amplitude equal to the output current. It follows that the resultant capacitive component of AC ripple voltage is a triangular waveform. Together with the ESR-related ripple component, the peak-to-peak ripple voltage amplitude is given by [Equation 22](#).

$$V_{IN(ripple)} = \frac{I_{OUT} \cdot D \cdot (1-D)}{F_{SW} \cdot C_{IN}} + I_{OUT} \cdot R_{ESR} \quad (22)$$

The input capacitance required for a load current, based on an input voltage ripple specification (ΔV_{IN}), is given by [Equation 23](#):

$$C_{IN} \geq \frac{I_{OUT} \cdot D \cdot (1-D)}{F_{SW} \cdot (V_{IN(ripple)} - I_{OUT} \cdot R_{ESR})} \quad (23)$$

The recommended high-frequency input capacitance is 2.2 μ F or higher. Ensure the input capacitor is a high-quality X7S or X7R ceramic capacitor with sufficient voltage rating for C_{IN} . Based on the voltage coefficient of ceramic capacitors, choose a voltage rating of twice the maximum input voltage. Additionally, some bulk capacitance is required if the LM5164 is not located within approximately 5 cm from the input voltage source. This capacitor provides parallel damping to the resonance associated with parasitic inductance of the supply lines and high-Q ceramics. See [Power Supply Recommendations](#) for more detail.

8.2.2.6 Type 3 Ripple Network

A Type 3 ripple generation network uses an RC filter consisting of R_A and C_A across SW and V_{OUT} to generate a triangular ramp that is in phase with the inductor current. This triangular ramp is then AC-coupled into the feedback node using capacitor C_B as shown in [Figure 12](#). Type 3 ripple injection is suited for applications where low output voltage ripple is crucial.

Calculate R_A and C_A using [Equation 24](#) and [Equation 25](#) to provide the required ripple amplitude at the FB pin.

$$C_A \geq \frac{10}{F_{SW} \cdot (R_{FB1} \parallel R_{FB2})} \quad (24)$$

For the feedback resistor values given in [Figure 12](#), [Equation 24](#) dictates a minimum C_A of 742 pF. In this design, a 3300 pF capacitance is chosen. This is done to keep R_A within practical limits between 100 k Ω and 1 M Ω when using [Equation 25](#).

$$R_A C_A \geq \frac{(V_{IN(nom)} - V_{OUT}) \cdot t_{ON(nom)}}{20mV} \quad (25)$$

Based on C_A set at 3.3 nF, R_A is calculated to be 453 k Ω to provide a 20-mV ripple voltage at FB. The general recommendation for a Type 3 network is to calculate R_A and C_A to get 20 mV of ripple at typical operating conditions, while ensuring a 12-mV minimum ripple voltage on FB at minimum V_{IN} .

While the amplitude of the generated ripple does not affect the output voltage ripple, it impacts the output regulation as it reflects as a DC error of approximately half the amplitude of the generated ripple. For example, a converter circuit with Type 3 network that generates a 40-mV ripple voltage at the feedback node has approximately 10-mV worse load regulation scaled up through the FB divider to V_{OUT} than the same circuit that generates a 20-mV ripple at FB. Calculate the coupling capacitance C_B using [Equation 26](#).

$$C_B \geq \frac{t_{TR-settling}}{3 \cdot R_{FB1}}$$

where

- $t_{TR-settling}$ is desired load transient response settling time (26)

C_B calculates to 56 pF based on a 75- μ s settling time. This value avoids excessive coupling capacitor discharge by the feedback resistors during sleep intervals when operating at light loads. To avoid capacitance fall-off with DC bias, use a C0G or NP0 dielectric capacitor for C_B .

8.2.3 Application Curves

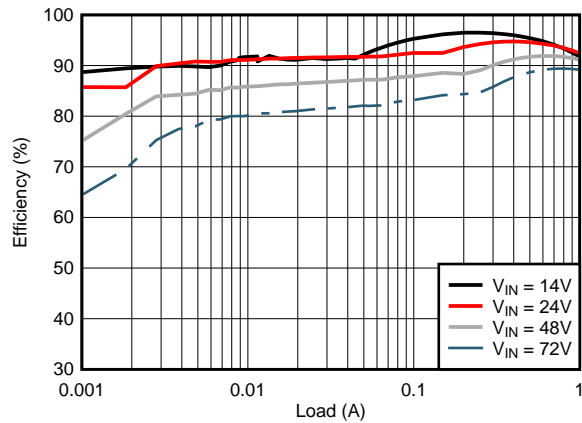


Figure 13. Conversion Efficiency (Log Scale)

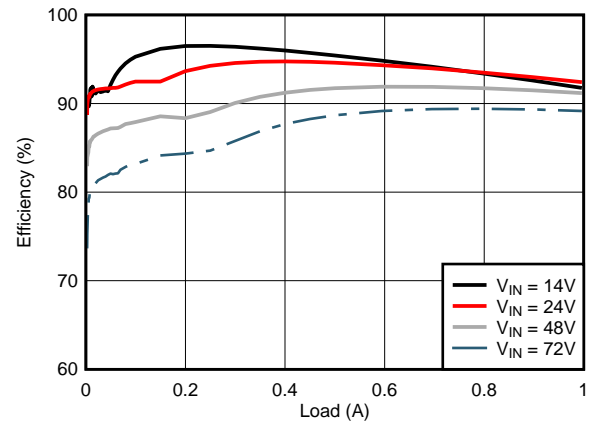


Figure 14. Conversion Efficiency (Linear Scale)

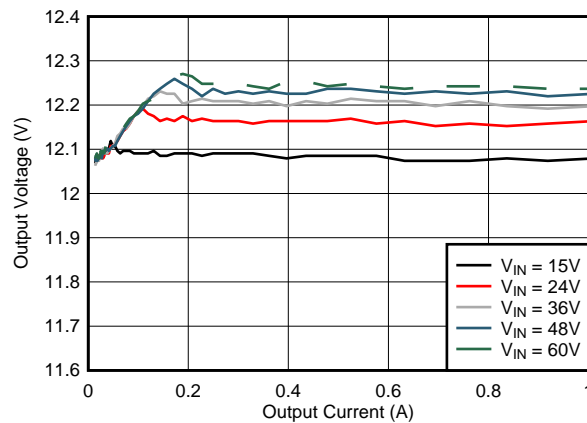
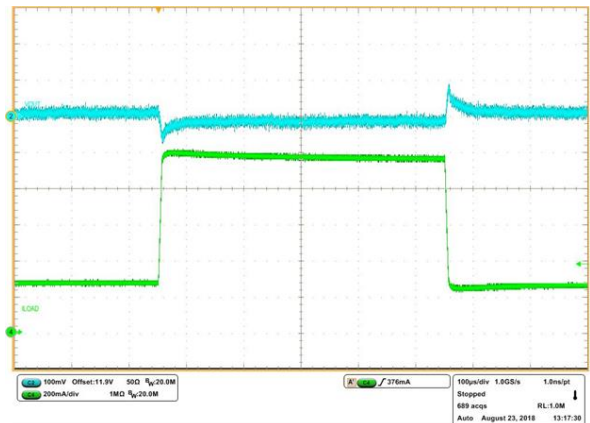


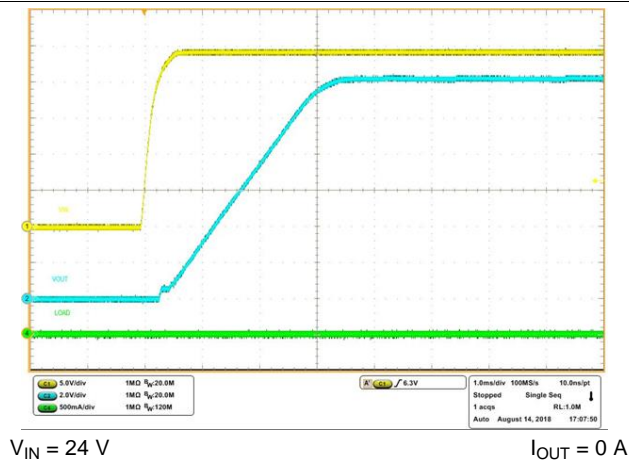
Figure 15. Load and Line Regulation Performance



$V_{IN} = 24\text{ V}$

$I_{OUT} = 0.25\text{ A to } 1\text{ A at } 0.1\text{ A}/\mu\text{s}$

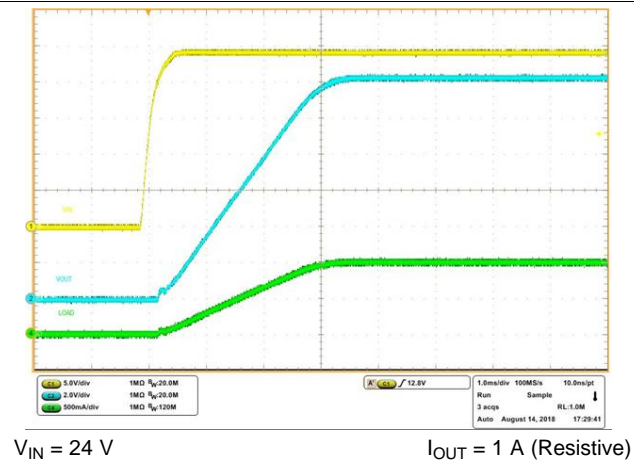
Figure 16. Load Step Response



$V_{IN} = 24\text{ V}$

$I_{OUT} = 0\text{ A}$

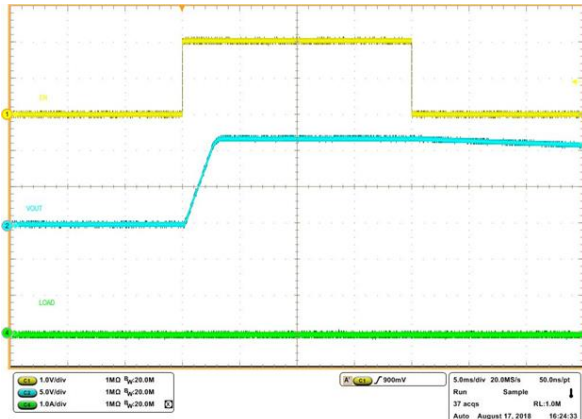
Figure 17. No-Load Start-up with V_{IN}



$V_{IN} = 24\text{ V}$

$I_{OUT} = 1\text{ A (Resistive)}$

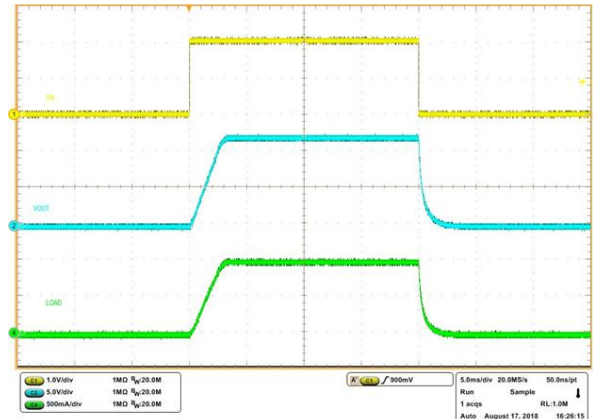
Figure 18. Full-Load Start-up with V_{IN}



$V_{IN} = 24\text{ V}$

$I_{OUT} = 0\text{ A}$

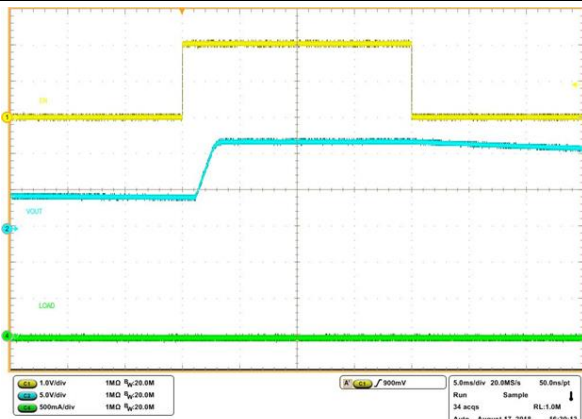
Figure 19. No-Load Start-up and Shutdown with EN/UVLO



$V_{IN} = 24\text{ V}$

$I_{OUT} = 1\text{ A (Resistive)}$

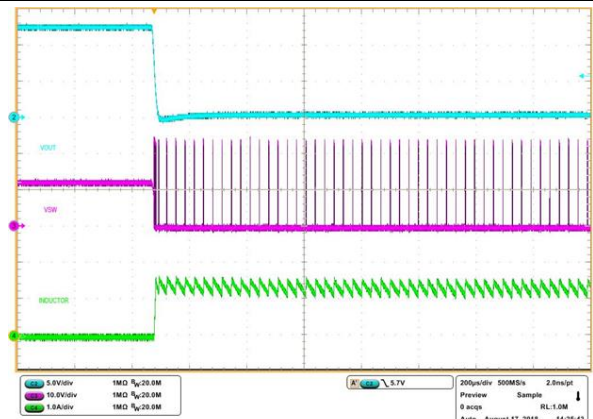
Figure 20. Full-Load Start-up and Shutdown with EN/UVLO



$V_{IN} = 24\text{ V}$

$I_{OUT} = 0\text{ A}$

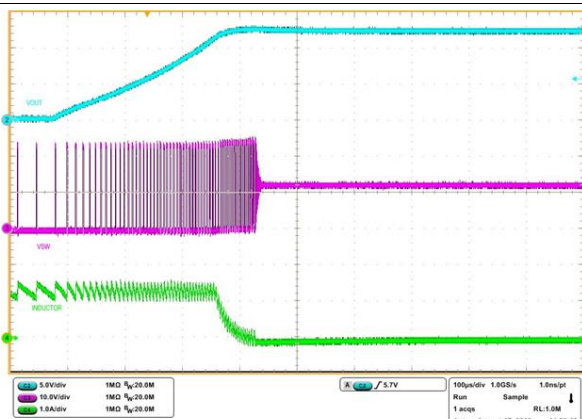
Figure 21. Pre-bias Start-up with EN/UVLO



$V_{IN} = 24\text{ V}$

Load = 0 A to Short

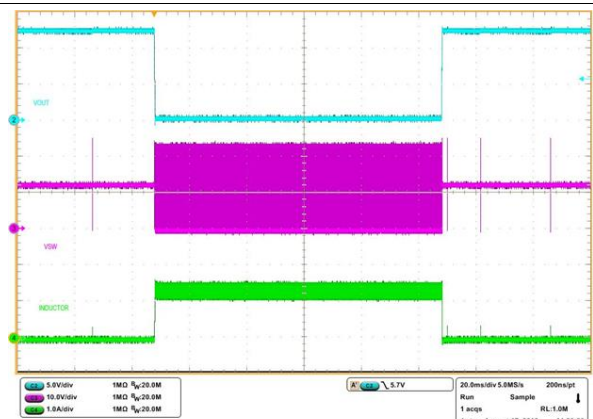
Figure 22. Short Circuit Applied



$V_{IN} = 24\text{ V}$

Load = Short to 0 A

Figure 23. Short Circuit Recovery



$V_{IN} = 24\text{ V}$

Load = 0 A to Short to 0 A

Figure 24. No Load to Short Circuit/Short Circuit Recovery

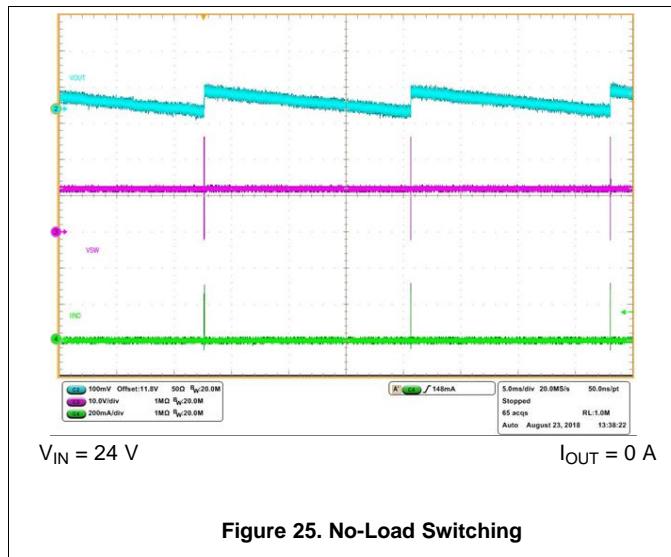


Figure 25. No-Load Switching

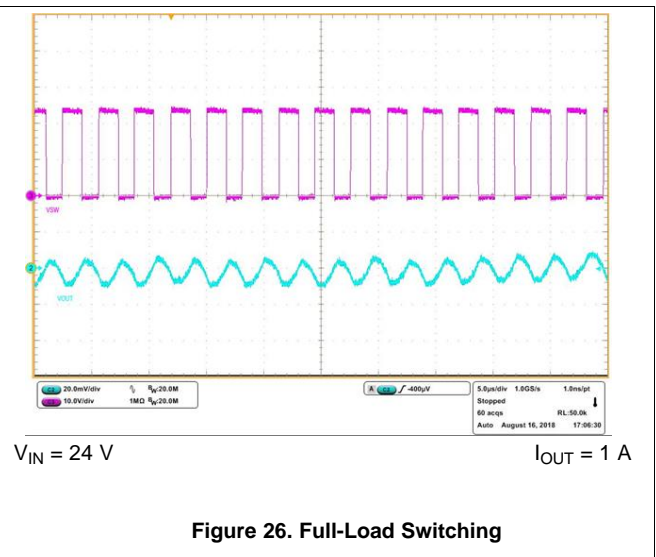


Figure 26. Full-Load Switching

9 Power Supply Recommendations

The LM5164 buck converter is designed to operate from a wide input voltage range between 6 V and 100 V. The characteristics of the input supply must be compatible with the [Absolute Maximum Ratings](#) and [Recommended Operating Conditions](#) tables. In addition, the input supply must be capable of delivering the required input current to the fully-loaded regulator. Estimate the average input current with [Equation 27](#).

$$I_{IN} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \cdot \eta}$$

where

- η is the efficiency

(27)

If the converter is connected to an input supply through long wires or PCB traces with a large impedance, take special care to achieve stable performance. The parasitic inductance and resistance of the input cables may have an adverse affect on converter operation. The parasitic inductance in combination with the low-ESR ceramic input capacitors form an underdamped resonant circuit. This circuit can cause overvoltage transients at VIN each time the input supply is cycled ON and OFF. The parasitic resistance causes the input voltage to dip during a load transient. If the converter is operating close to the minimum input voltage, this dip can cause false UVLO fault triggering and a system reset. The best way to solve such issues is to reduce the distance from the input supply to the regulator and use an aluminum electrolytic input capacitor in parallel with the ceramics. The moderate ESR of the electrolytic capacitor helps to damp the input resonant circuit and reduce any voltage overshoots. A 10-μF electrolytic capacitor with a typical ESR of 0.5 Ω provides enough damping for most input circuit configurations.

An EMI input filter is often used in front of the regulator that, unless carefully designed, can lead to instability as well as some of the effects mentioned above. The application report [Simple Success with Conducted EMI for DC-DC Converters](#) (SNVA489) provides helpful suggestions when designing an input filter for any switching regulator.

10 Layout

10.1 Layout Guidelines

PCB layout is a critical portion of good power supply design. There are several paths that conduct high slew-rate currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise and EMI or degrade the power supply performance.

1. To help eliminate these problems, bypass the VIN pin to GND with a low-ESR ceramic bypass capacitor with a high-quality dielectric. Place C_{IN} as close as possible to the LM5164 VIN and GND pins. Grounding for both the input and output capacitors should consist of localized top-side planes that connect to the GND pin and GND PAD.
2. Minimize the loop area formed by the input capacitor connections to the VIN and GND pins.
3. Locate the inductor close to the SW pin. Minimize the area of the SW trace or plane to prevent excessive capacitive coupling.
4. Tie the GND pin directly to the power pad under the device and to a heat-sinking PCB ground plane.
5. Use a ground plane in one of the middle layers as a noise shielding and heat dissipation path.
6. Have a single-point ground connection to the plane. Route the ground connections for the feedback, soft-start, and enable components to the ground plane. This prevents any switched or load currents from flowing in analog ground traces. If not properly handled, poor grounding results in degraded load regulation or erratic output voltage ripple behavior.
7. Make V_{IN} , V_{OUT} and ground bus connections as wide as possible. This reduces any voltage drops on the input or output paths of the converter and maximizes efficiency.
8. Minimize trace length to the FB pin. Place both feedback resistors, R_{FB1} and R_{FB2} , close to the FB pin. Place C_{FF} (if needed) directly in parallel with R_{FB1} . If output setpoint accuracy at the load is important, connect the V_{OUT} sense at the load. Route the V_{OUT} sense path away from noisy nodes and preferably through a layer on the other side of a grounded shielding layer.
9. The RON pin is sensitive to noise. Thus, locate the R_{RON} resistor as close as possible to the device and route with minimal lengths of trace. The parasitic capacitance from RON to GND must not exceed 20 pF.
10. Provide adequate heat sinking for the LM5164 to keep the junction temperature below 150°C. For operation at full rated load, the top-side ground plane is an important heat-dissipating area. Use an array of heat-sinking vias to connect the exposed pad to the PCB ground plane. If the PCB has multiple copper layers, these thermal vias must also be connected to inner layer heat-spreading ground planes.

10.1.1 Compact PCB Layout for EMI Reduction

Radiated EMI generated by high di/dt components relates to pulsing currents in switching converters. The larger area covered by the path of a pulsing current, the more electromagnetic emission is generated. The key to minimizing radiated EMI is to identify the pulsing current path and minimize the area of that path.

The critical switching loop of the buck converter power stage in terms of EMI is denoted in [Figure 27](#). The topological architecture of a buck converter means that a particularly high di/dt current path exists in the loop comprising the input capacitor and the integrated MOSFETs of the LM5164, and it becomes mandatory to reduce the parasitic inductance of this loop by minimizing the effective loop area.

Layout Guidelines (continued)

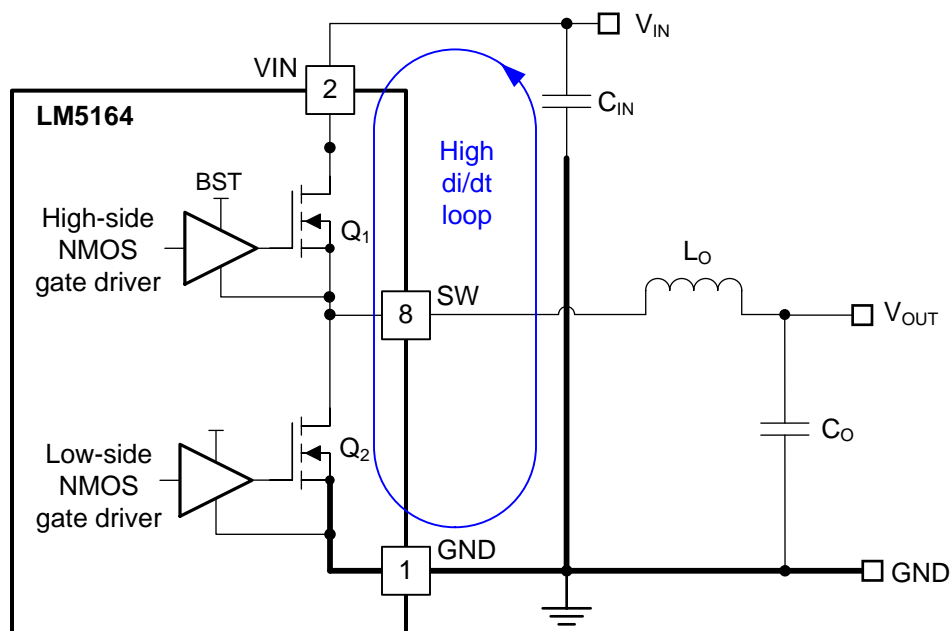


Figure 27. DC/DC Buck Converter With Power Stage Circuit Switching Loop

The input capacitor provides the primary path for the high di/dt components of the high-side MOSFET's current. Placing a ceramic capacitor as close as possible to the VIN and GND pins is the key to EMI reduction. Keep the trace connecting SW to the inductor as short as possible and just wide enough to carry the load current without excessive heating. Use short, thick traces or copper pours (shapes) for current conduction path to minimize parasitic resistance. Place the output capacitor close to the V_{OUT} side of the inductor, and connect the capacitor's return terminal to the GND pin and exposed PAD of the LM5164.

10.1.2 Feedback Resistors

Reduce noise sensitivity of the output voltage feedback path by placing the resistor divider close to the FB pin, rather than close to the load. This reduces the trace length of FB signal and noise coupling. The FB pin is the input to the feedback comparator, and as such is a high impedance node sensitive to noise. The output node is a low impedance node, so the trace from V_{OUT} to the resistor divider can be long if a short path is not available.

Route the voltage sense trace from the load to the feedback resistor divider, keeping away from the SW node, the inductor and V_{IN} to avoid contaminating the feedback signal with switch noise, while also minimizing the trace length. This is most important when high feedback resistances, greater than 100 k Ω , are used to set the output voltage. Also, route the voltage sense trace on a different layer from the inductor, SW node and V_{IN}, such that there is a ground plane that separates the feedback trace from the inductor and SW node copper polygon. This provides further shielding for the voltage feedback path from switching noise sources.

10.2 Layout Example

Figure 28 shows an example layout for the PCB top layer of a 2-layer board with essential components placed on the top side.

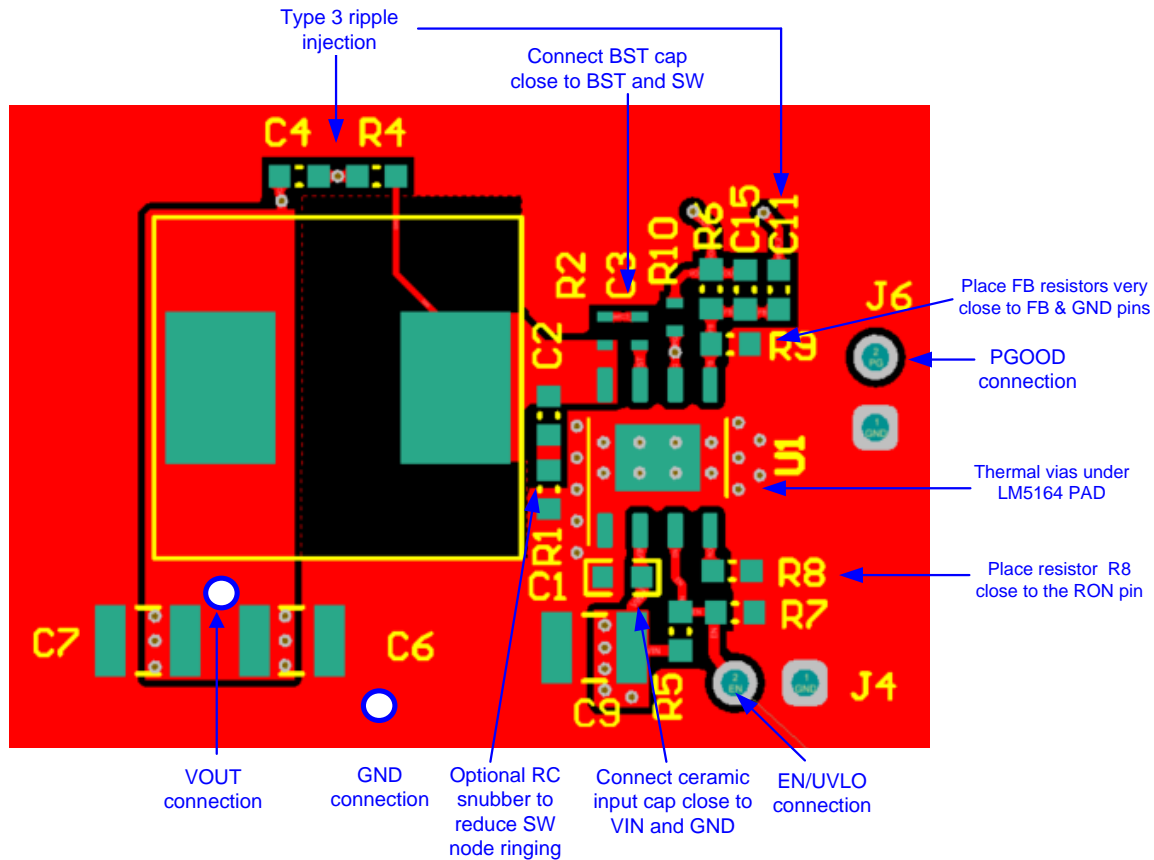


Figure 28. LM5164 Single-Sided PCB Layout Example

11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

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11.1.2 Development Support

- LM5164 [Quickstart Calculator](#)
- LM5164 [Simulation Models](#)
- For TI's Reference Design Library, visit [TIDesigns](#)
- For TI's WEBENCH Design Environment, visit the [WEBENCH® Design Center](#)

11.1.2.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the LM5164 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

11.2 Related Documentation

For related documentation see the following:

- [LM5164-Q1EVM-041 EVM user's guide](#) (SNVU620)
- [Selecting an ideal ripple generation network for your COT buck converter](#) (SNVA776)
- White Papers:
 - [Valuing wide \$V_{IN}\$, low-EMI synchronous buck circuits for cost-effective, demanding applications](#)
 - [An overview of conducted emi specifications for power supplies](#)
 - [An overview of radiated emi specifications for power supplies](#)
- TI Designs:
 - [TIDA-01395 24-V AC Power stage with wide \$V_{IN}\$ converter and battery gauge for smart thermostat](#) (TIDUCW0)
- Power House Blogs:
 - [Use a low-quiescent-current switcher for high-voltage conversion](#)
- Industrial Strength Blogs:
 - [Powering smart sensor transmitters in industrial applications](#)
 - [Industrial Strength design – part 1](#)
 - [Trends in building automation: predictive maintenance](#)
 - [Trends in building automation: connected sensors for user comfort](#)
- [AN-2162: Simple success with conducted EMI from DC/DC converters](#) (SNVA489)
- [Automotive cranking simulator user's guide](#) (SLVU984)

Related Documentation (continued)

- [Using new thermal metrics](#) (SBVA025)
- [Semiconductor and IC package thermal metrics](#) (SPRA953)

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments.
WEBENCH is a registered trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| LM5164DDAR | ACTIVE | SO PowerPAD | DDA | 8 | 2500 | Green (RoHS & no Sb/Br) | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 150 | LM5164 | Samples |
| LM5164DDAT | ACTIVE | SO PowerPAD | DDA | 8 | 250 | Green (RoHS & no Sb/Br) | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 150 | LM5164 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LM5164 :

- Automotive: [LM5164-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM5164DDAR | SO Power PAD | DDA | 8 | 2500 | 330.0 | 12.8 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LM5164DDAT | SO Power PAD | DDA | 8 | 250 | 330.0 | 12.8 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

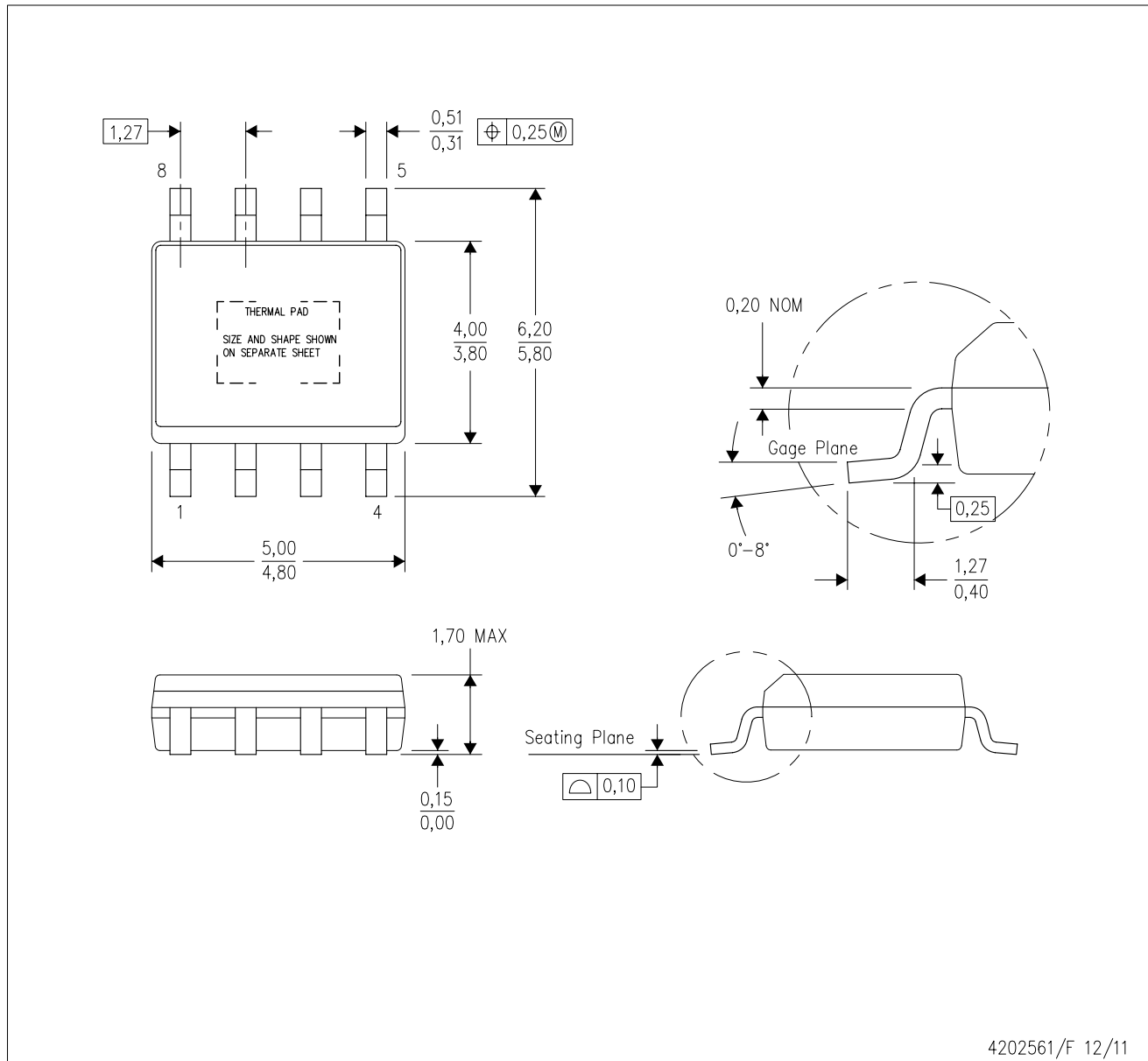


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM5164DDAR | SO PowerPAD | DDA | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LM5164DDAT | SO PowerPAD | DDA | 8 | 250 | 366.0 | 364.0 | 50.0 |

DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL-OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.

DDA (R-PDSO-G8)

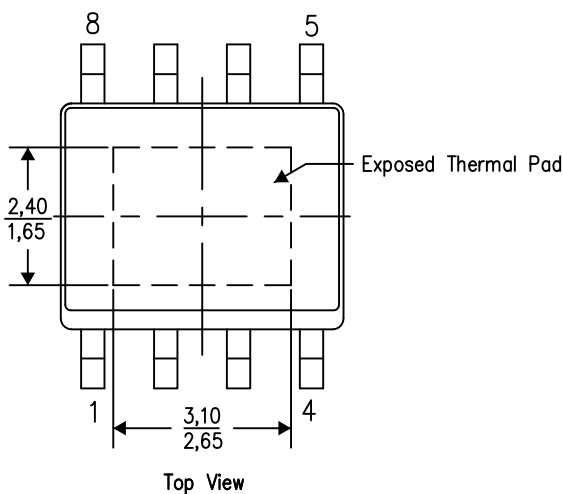
PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

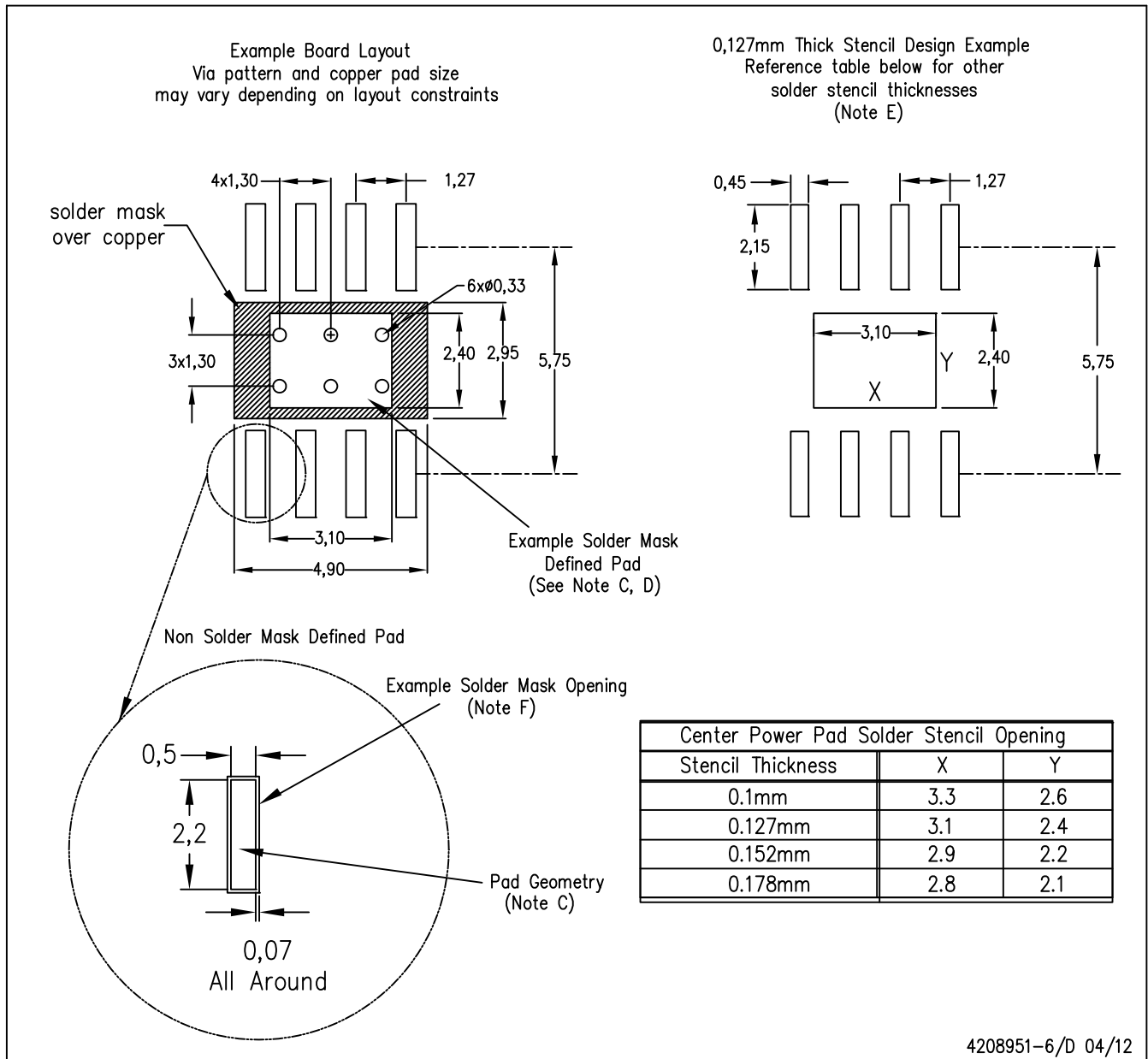
4206322-6/L 05/12

NOTE: A. All linear dimensions are in millimeters

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DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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